High Power Switch - LNA Module 0.4 - 5.0 GHz



MAIA-011004

Rev. V3

Features

- 2-Stage LNA and High Power Switch
- High RF Input Power:

120 W CW @ +85°C, 2.0 GHz 100 W CW @ +85°C, 2.7 GHz

Noise Figure:

0.85 dB @ 2.0 GHz 1.0 dB @ 2.7 GHz

· Gain:

37 dB @ 2.0 GHz 34 dB @ 2.7 GHz

- OIP3: 36 dBm
- Lead-Free 5 mm 32-lead HQFN
- Integrated ESD Protection
- Halogen-Free "Green" Mold Compound
- ROHS* Compliant

Description

The MAIA-011004 is a compact surface mount module containing a PIN diode switch and two low noise amplifiers assembled in a 5 mm 32-lead HQFN plastic package. It was designed to be used at the input of the receive chain of TDD cellular base stations.

This module operates from 0.4 GHz to 5.0 GHz and features high power handling, very low noise figure and excellent linearity.

The connection between the output of LNA1 and the input of LNA2 is made outside of the module, making it possible for the user to add an attenuator or a filter.

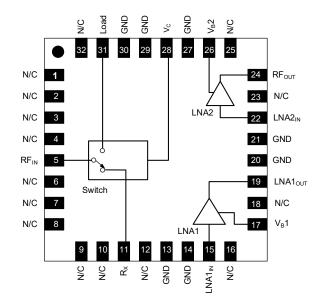
The MAIA-011004 is ideally suited for 4G and next generation 5G base stations at 1.9, 2.3, 2.6, 3.5, and 4.5 GHz.

Ordering Information^{1,2}

Part Number	Package		
MAIA-011004-TR1000	1k Piece Reel		
MAIA-011004-TR3000	3k Piece Reel		
MAIA-011004-1SMB	2 - 3 GHz Sample Board		
MAIA-011004-2SMB	3 - 4 GHz Sample Board		

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts.

Functional Schematic



Pin Configuration

Pin#	Pin Name	Function	
1-4, 6-10,12 16,18,23,25,32	N/C ³	No Connection	
5	RF _{IN}	RF Input / Bias	
11	R _X	R _X Switch Output	
13,14,20,21, 27,29,30	GND	RF Ground	
15	LNA1 _{IN}	LNA1 Input	
17	V _B 1	LNA1 Bias	
19	LNA1 _{OUT}	LNA1 Output / V _{DD} 1	
22	LNA2 _{IN}	LNA2 Input	
24	RF _{OUT}	RF Output / V _{DD} 2	
26	V _B 2	LNA2 Bias	
28	V _C	Switch Bias Control	
31	Load	T _X Switch Output	
33	Paddle	Ground⁴	

- MACOM recommends connecting unused package pins (N/C) to ground.
- The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

High Power Switch - LNA Module 0.4 - 5.0 GHz



MAIA-011004

Rev. V3

Electrical Specifications⁵:

 T_{A} = +25°C, V_{DD} 1 = 3 V, V_{BB} 1 = 3 V, V_{DD} 2 = 3 V, V_{BB} 2 = 3 V Switch Bias = (see Bias Table), R_{BIAS} 2 = 133 Ω, R_{BIAS} 1 = 100 Ω, Z_{0} = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Input RF Power @ +85°C RF _{IN} - LOAD	2.0 GHz 2.7 GHz 3.5 GHz	W	_	120 100 80	_
Insertion Loss RF _{IN} - LOAD	2.0 GHz 2.7 GHz 3.5 GHz	dB	_	0.15 0.18 0.21	_
Noise Figure RF _{IN -} RF _{OUT}	2.0 GHz 2.7 GHz 3.5 GHz	dB	_	0.85 1.00 1.25	_
Gain RF _{IN -} RF _{OUT}	2.0 GHz 2.7 GHz 3.5 GHz	dB	_	37 34 32	_
Isolation RF _{IN} - LNA1 _{IN}	Switch State = RF _{IN} - LOAD 2.7 GHz	dB	_	41	_
Isolation LNA1 _{OUT} - LNA2 _{IN}	Switch State = RF _{IN} - RF _{OUT} 2.7 GHz	dB	_	40	_
Output IP3 RF _{IN -} RF _{OUT}	P _{IN} = -35 dBm, Tones 11 MHz apart 2.7 GHz	dBm	_	36	_
LNA Bias Current	LNA1 Current: I _{DD} 1 + IV _B 1 LNA2 Current: I _{DD} 2 + IV _B 2	mA	_	75 65	_

^{5.} Refer to LNA biasing options on page 4.

Switch Bias Table (See Sample Board Schematic on Page 9)

RF _{IN} – LOAD	RF _{IN} – RF _{OUT}	LOAD_B	R _x Bias	Rx_ShD_B	V_RF _{IN}
ON	OFF	0 V (-50 mA)	+28 V (50 mA)	0 V (-50 mA)	3 V (50 mA)
OFF	ON	+28 V (0 mA)	0 V (-50 mA)	+28 V (0 mA)	3 V (50 mA)



Rev. V3

Absolute Maximum Ratings^{6,7,8}

Parameter	Absolute Maximum
RF Input Power RF _{IN -} RF _{OUT} RF _{IN} - LOAD	19 dBm See Power De-rating Curve
Switch Reverse Voltage (RF & DC)	160 V
V _B 1 & V _B 2	5.0 V
LNA1 _{OUT} & RF _{OUT}	5.5 V
Junction Temperature Switch LNA ⁹	+175°C +150°C
Operating Temperature	-40°C to +100°C
Storage Temperature	-55°C to +150°C

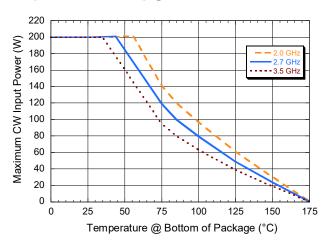
- 6. Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.
- 8. Operating at nominal conditions with $T_J \le$ Absolute Maximum will ensure MTTF >1 x 10⁶ hours.
- 9. LNA Junction Temperature $(T_J) = T_C + \Theta_{JC}^*(V^*I)$ Typical thermal resistance $(\Theta_{JC}) = 83^{\circ}C/W$
 - a) For $T_C = +25^{\circ}C$,

 $T_J = 56^{\circ}C @ V_{DD}1 = 5 V$, 75 mA for LNA1 $T_J = 52^{\circ}C @ V_{DD}2 = 5 V$, 65 mA for LNA2

b) For $T_C = +100$ °C,

 T_J = 131°C @ V_{DD} 1 = 5 V, 75 mA for LNA1 T_J = 127°C @ V_{DD} 1 = 5 V, 65 mA for LNA2

T_X Input Power De-rating @ 20 dB I/O Return Loss



Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Parameter	Rating	Standard	
Human Body Model	500 V	ESDA / JEDEC	
(HBM)	(Class 1B)	JS-001	
Charged Device	1000 V	JEDEC	
Model (CDM)	(Class C3)	JESD22-C101	



Rev. V3

LNA Biasing Options

LNA1 and LNA2 biases can be set in 2 different ways: using only V_{DD} , or using separate V_{DD} and V_{BIAS} [V_B] voltages. A separate V_{BIAS} voltage allows V_{B1} and V_{B2} to be used as enable pins to power LNA1 and LNA2 up and down during operation.

For both bias methods, select the value of R_{BIAS} 1 and R_{BIAS} 2 to achieve the desired currents using the plots on page 5. LNA1 current should not exceed 100 mA @ 25 °C and likewise LNA2 current should not exceed 95 mA @ 25 °C. DC blocking capacitors must be used at the LNA1 and 2 input and output ports (see diagram).

Biasing Option - V_{DD} only

To use only V_{DD} , connect to $V_{DD}[1,2]$ through an RF inductor and connect $V_{B}[1,2]$ to the corresponding V_{DD} through bias resistor $R_{BIAS}[1,2]$ as shown in Figure 1.

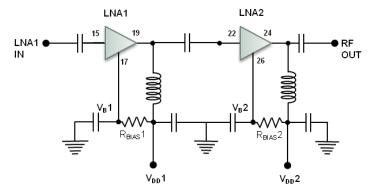


Figure 1

Biasing Option - Separate V_{DD} and V_{BB} Voltages (V_{BB} ≤ V_{DD})

To use separate V_{DD} and V_{BB} voltages, connect to V_{DD} [1,2] through an RF inductor and connect to V_{BB} [1,2] through bias resistor R_{BIAS} [1,2] as shown in Figure 2. Typical current draw for V_{B} [1,2] is 1.4 mA @ V_{BB} = 3 V ,and 1 μ A @ V_{BB} = 0 V. Typical current draw for V_{DD} [1,2] is < 1 μ A @ V_{BB} = 0 V and V_{DD} = 3V.

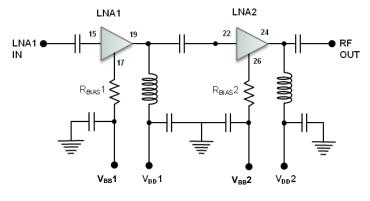


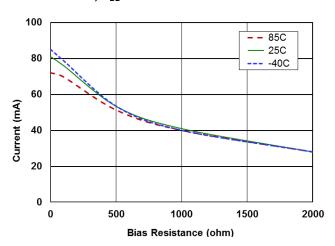
Figure 2



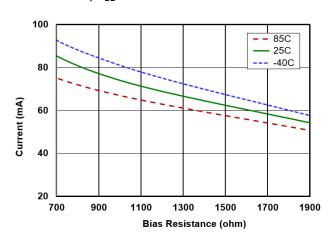
Rev. V3

Typical Performance Curves: LNA1 Bias Current over Temperature

LNA1 Current, $V_{DD}1 = 3 V$

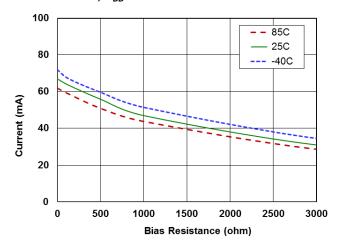


LNA1 Current, $V_{DD}1 = 5 V$

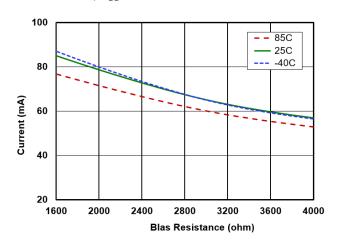


Typical Performance Curves: LNA2 Bias Current over Temperature

LNA2 Current, $V_{DD}2 = 3 V$



LNA2 Current, $V_{DD}2 = 5 V$



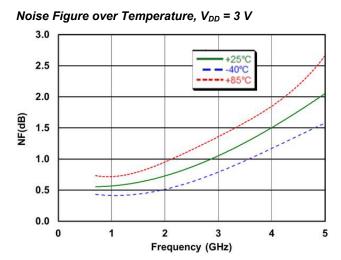


Rev. V3

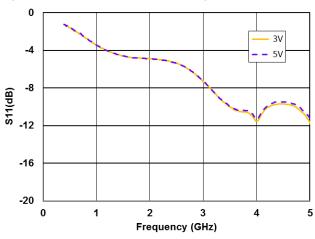
Typical Performance Curves: $T_A = +25^{\circ}C$, $Z_0 = 50 \Omega$, $V_{DD} = 3 V$, Switch State = RF_{IN} - RF_{OUT}

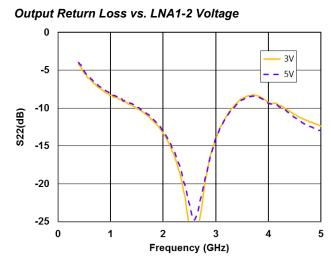
Gain vs. LNA1-2 Voltage

60
50
40
20
10
0 1 2 3 4 5
Frequency (GHz)

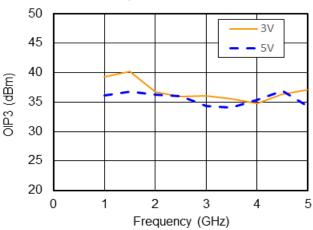


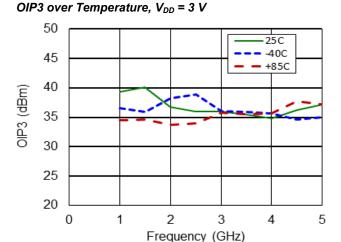
Input Return Loss vs. LNA1-2 Voltage





OIP3 vs. LNA1-2 Voltage





MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

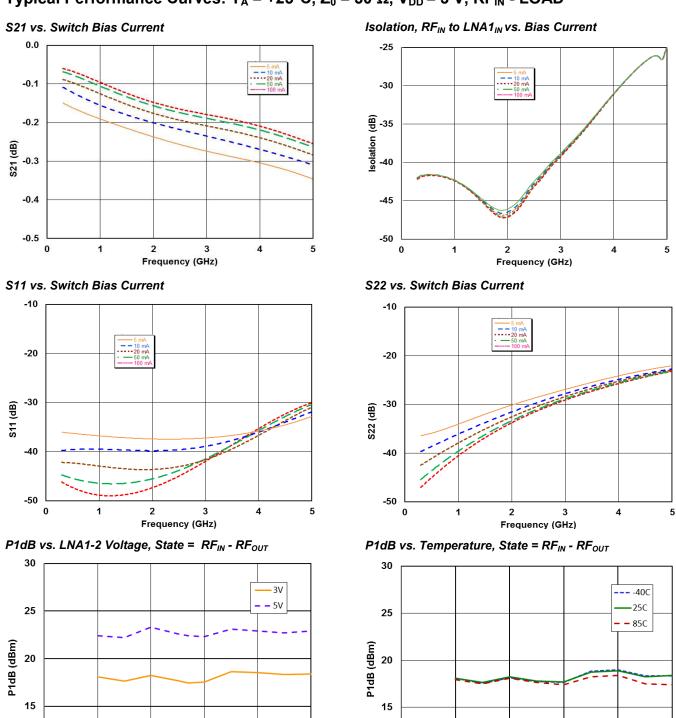
Visit www.macom.com for additional data sheets and product information.

6



Rev. V3

Typical Performance Curves: $T_A = +25^{\circ}C$, $Z_0 = 50 \Omega$, $V_{DD} = 3 V$, RF_{IN} - LOAD



MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

Visit www.macom.com for additional data sheets and product information.

5

10

0

1

2

Frequency (GHz)

1

2

Frequency (GHz)

3

4

10

0

5

3



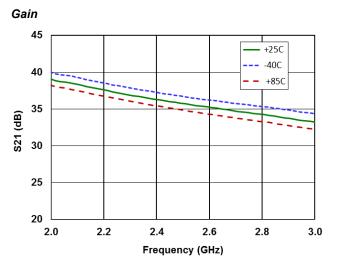
Rev. V3

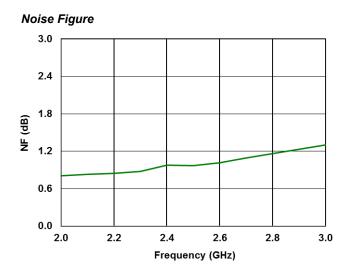
Electrical Specifications: T_A = +25°C, V_{DD} 1 = 3 V, V_{BB} 1 = 3 V, V_{DD} 2 = 3 V, V_{BB} 2 = 3 V, Switch Bias = (see Bias Table), R5 = 133 Ω^{10} , R7 = 100 Ω^{10} ; Tuned for 2 - 3 GHz band

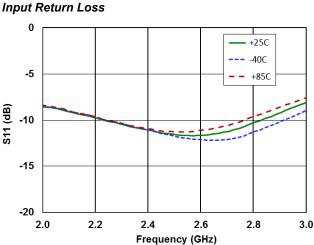
Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	RF _{IN} – RF _{OUT} , 2.7GHz	dB	31	34	_
Noise Figure	RF _{IN} – RF _{OUT} , 2.7GHz	dB	-	1.1	1.5
Input Return Loss	RF _{IN} – RF _{OUT} , 2.7GHz	dB	-	11	_
Output Return Loss	RF _{IN} – RF _{OUT} , 2.7GHz	dB	_	18	_
LNA Bias Current	LNA1 Current: I _{DD} 1 + IV _B 1 LNA2 Current: I _{DD} 2 + IV _B 2	mA	_	75 65	_

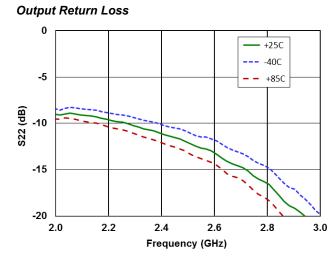
^{10.} Refer to LNA Sample Board Schematic on page 9.

Typical Performance Curves: 2 - 3 GHz tuned Sample Board, RFIN - RFOUT









8

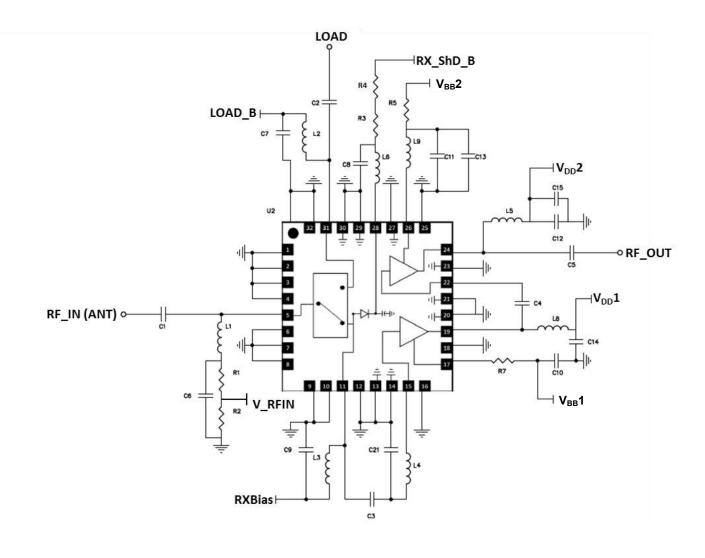
MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

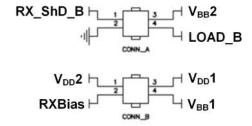
Visit www.macom.com for additional data sheets and product information.



Rev. V3

Schematic: MAIA-011004 Sample Board

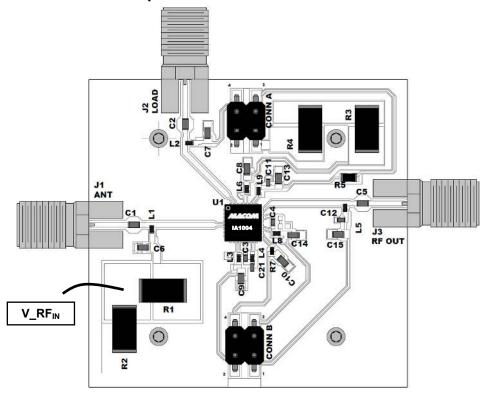






Rev. V3

PCB Layout: MAIA-011004 Sample Board



Sample Board Parts List* for 2 - 3 GHz Tuned PCB

Part	Value	Description	MFR Part #	
C1, C2, C5,	27 pF / 250 V	0603 SMT Capacitor	ATC600S270GT250T	
C3	22 pF / 250 V	0402 SMT Capacitor	ATC600L220FT200T	
C4	3.3 pF / 50 V	0402 SMT Capacitor	GRM1555C1H3R3BA01D	
C6, C7,C8, C9, C10, C13, C14, C15	4.7 μF / 35 V	0603 SMT Capacitor	_	
C11	10 nF / 25V	0402 SMT Capacitor	_	
C12	1 nF / 25V	0402 SMT Capacitor	_	
C21	0.40 pF ±0.1 pF	0402 SMT Capacitor	GJM1555C1HR40BB01	
L1, L2, L3, L5 ,L6, L9	68 nH / 100 mA	0402 SMT Inductor	0402CS-68NXJLW	
L4	2.7 nH	0402 SMT Inductor	0402CS-2N7XJLU	
L8	2.0 nH	0402 SMT Inductor	0402CS-2N0XJLU	
R1	45 Ω / 1.0 W	2512 SMT Resistor	_	
R3, R4	270 Ω / 1.0 W	2512 SMT Resistor	_	
R5 (R _{BIAS} 2)	133 Ω	0805 SMT Resistor	_	
R7 (R _{BIAS} 1)	100 Ω	0402 SMT Resistor	_	
J1 - J3	SMA END LAUNCH	RF CONNECTOR	142-0761-821	
R2, C16, C18, C19, C20, C22		do not populate		
* Aluminum heat sink mounted to backside of PCB is not shown				

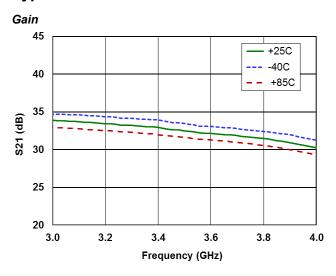


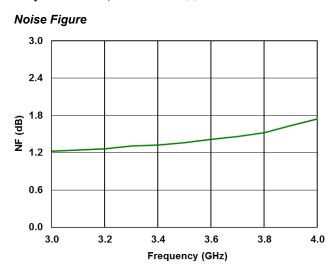
Rev. V3

Electrical Specifications: $T_A = +25^{\circ}C$, $V_{DD}1 = 3$ V, $V_{BB}1 = 3$ V, $V_{DD}2 = 3$ V, $V_{BB}2 = 3$ V, Switch Bias = (see Bias Table), R5 = 133 Ω^{10} , R7 = 100 Ω^{10} ; Tuned for 3 - 4 GHz band

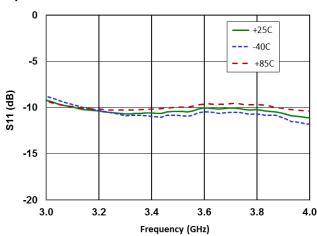
Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	RF _{IN} – RF _{OUT} , 3.5 GHz	dB	_	32	_
Noise Figure	RF _{IN} – RF _{OUT} , 3.5 GHz	dB	_	1.3	_
Input Return Loss	RF _{IN} – RF _{OUT} , 3.5 GHz	dB	_	12	_
Output Return Loss	RF _{IN} – RF _{OUT} , 3.5 GHz	dB	_	14	_
LNA Bias Current	LNA1 Current: I _{DD} 1 + IV _B 1 LNA2 Current: I _{DD} 2 + IV _B 2	mA	_	75 65	_

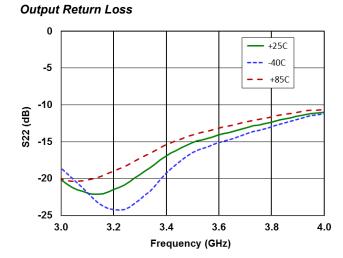
Typical Performance Curves: 3 - 4 GHz tuned Sample Board, RFIN - RFOUT





Input Return Loss





MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

Visit www.macom.com for additional data sheets and product information.

11



Rev. V3

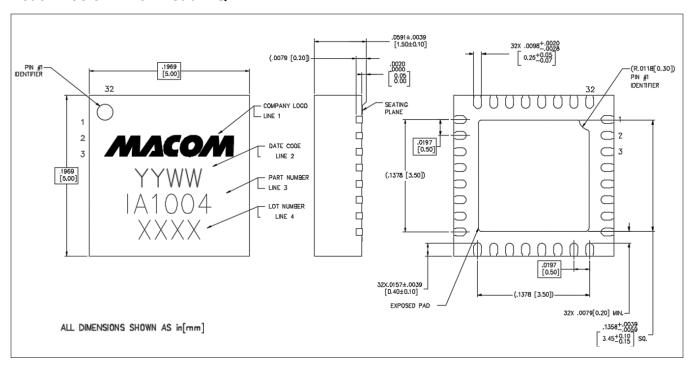
Sample Board Parts List* for 3 - 4 GHz Tuned PCB

Part	Value	Description	MFR Part #		
C1, C2, C5	27 pF / 250 V	0603 SMT Capacitor	ATC600S270GT250T		
C3	22 pF / 250 V	0402 SMT Capacitor	ATC600L220FT200T		
C4, C12	1000 pF / 25 V	0402 SMT Capacitor	_		
C6, C7,C8, C9, C10, C13, C14, C15	4.7 μF / 35 V	0603 SMT Capacitor	_		
C11	10 nF / 25V	0402 SMT Capacitor	_		
C21	0.50 pF ±0.1 pF	0402 SMT Capacitor	GJM1555C1HR50BB01		
L1, L2, L3, L5 ,L6, L9	68 nH / 100 mA	0402 SMT Inductor	0402CS-68NXJLW		
L4	1.2 nH	0402 SMT Inductor	0402CS-1N2XJLU		
L8	2.0 nH	0402 SMT Inductor	0402CS-2N0XJLU		
R1	45 Ω / 1.0 W	2512 SMT Resistor	_		
R3, R4	270 Ω / 1.0 W	2512 SMT Resistor	_		
R5 (R _{BIAS} 2)	133 Ω	0805 SMT Resistor	_		
R7 (R _{BIAS} 1)	100 Ω	0402 SMT Resistor	_		
J1 - J3	SMA END LAUNCH	RF CONNECTOR	142-0761-821		
R2, C16, C18, C19, C20, C22	22, C16, C18, C19, C20, C22 do not populate				
*	* Aluminum heat sink mounted to backside of PCB is not shown				



Rev. V3

Lead-Free 5 mm 32-Lead HQFN[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is NiPdAuAg.

High Power Switch - LNA Module 0.4 - 5.0 GHz



MAIA-011004

Rev. V3

MACOM Technology Solutions Inc. ("MACOM"). All rights reserved.

These materials are provided in connection with MACOM's products as a service to its customers and may be used for informational purposes only. Except as provided in its Terms and Conditions of Sale or any separate agreement, MACOM assumes no liability or responsibility whatsoever, including for (i) errors or omissions in these materials; (ii) failure to update these materials; or (iii) conflicts or incompatibilities arising from future changes to specifications and product descriptions, which MACOM may make at any time, without notice. These materials grant no license, express or implied, to any intellectual property rights.

THESE MATERIALS ARE PROVIDED "AS IS" WITH NO WARRANTY OR LIABILITY, EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHT, ACCURACY OR COMPLETENESS, OR SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES WHICH MAY RESULT FROM USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.